

# SPICE Device Model Si8901EDB

## **Vishay Siliconix**

## Bi-Directional P-Channel 20-V (D-S) MOSFET

#### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

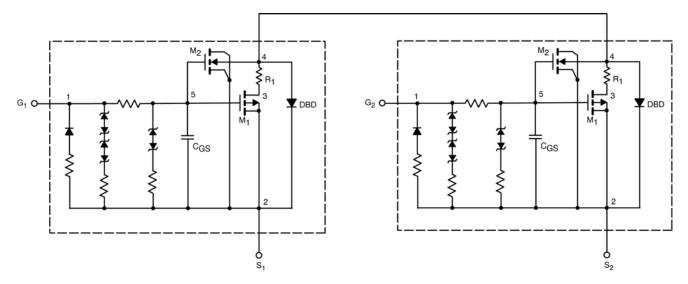
- · Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 5-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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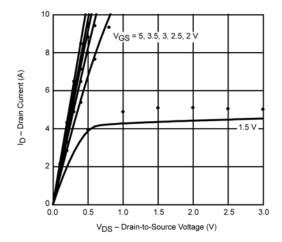
SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{SS} = V_{GS}$ , $I_D = -250 \mu A$	0.49		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{SS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	42		Α
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_{SS} = -1 \text{ A}$	0.046	0.048	Ω
		$V_{GS} = -2.5 \text{ V}, I_{SS} = -1 \text{ A}$	0.060	0.062	
		$V_{GS} = -1.8 \text{ V}, I_{SS} = -1 \text{ A}$	0.075	0.081	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{SS} = -10 \text{ V}, I_{SS} = -1 \text{ A}$	6.2	7	S
Dynamic <sup>b</sup>	•		-	-	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{SS} = -10 \text{ V, } R_L = 10 \Omega$ $I_{SS} \cong -1 \text{ A, } V_{GEN} = -4.5 \text{ V, } R_G = 6 \Omega$	2	2.3	μ <b>s</b>
Rise Time	t <sub>r</sub>		2	2.2	
Turn-Off Delay Time	$t_{d(off)}$		2.1	1.3	
Fall Time	t <sub>f</sub>		7	9	

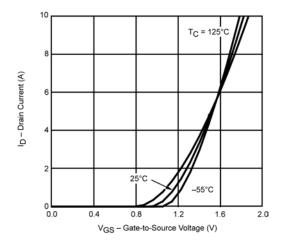
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%. b. Guaranteed by design, not subject to production testing.

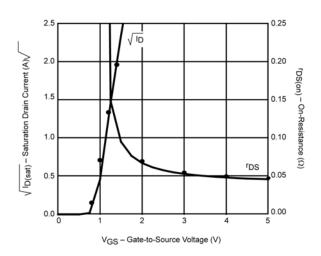


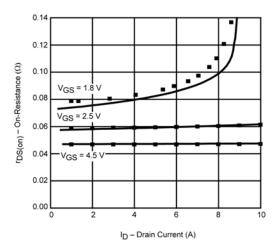
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#### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)









Note: Dots and squares represent measured data





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